

CATV Amplifier Module

Features

- Excellent Distortion Performance
- Low Power Consumption
- Capable of Handling Multiple Channels in the Return Path with Good Distortion Performance
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

Applications

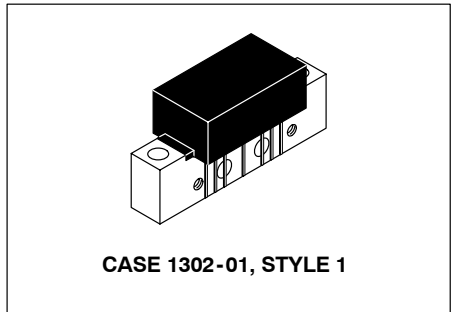
- CATV Systems Operating in the 5 to 75 MHz Frequency Range
- Specified for Use as a Return Path Amplifier for Low-Split 2-Way Cable TV Systems

Description

- 24 Vdc Supply, 5 to 75 MHz, CATV Reverse Amplifier

MHW1304LC

**5-75 MHz, 30.8 dB
CATV LOW CURRENT AMPLIFIER**



ARCHIVE INFORMATION

ARCHIVE INFORMATION

Table 1. Maximum Ratings

Parameter	Symbol	Value	Unit
DC Supply Voltage	V_{CC}	+28	Vdc
RF Input Voltage (Single Tone)	V_{in}	+60	dBmV
Operating Case Temperature Range	T_C	- 20 to +100	°C
Storage Temperature Range	T_{stg}	- 40 to +100	°C

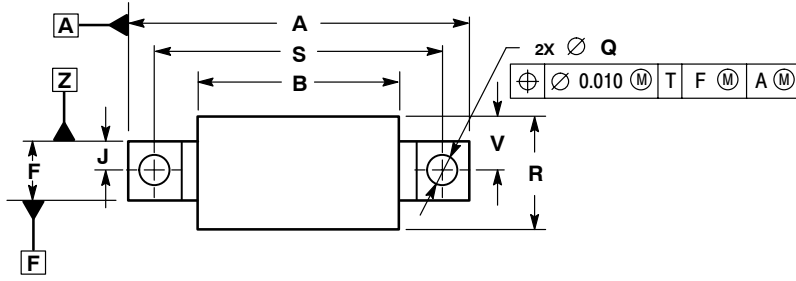
Table 2. Electrical Characteristics ($V_{CC} = 24$ Vdc, $T_C = 30^\circ\text{C}$, 75 Ω system, unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Bandwidth All	BW	5	—	75	MHz
Power Gain (f = 5 MHz)	G_p	30	30.8	31.2	dB
Slope (5-75 MHz)	S	- 0.2	—	0.5	dB
Gain Flatness (Peak To Valley) (5-75 MHz)	G_F	—	—	0.5	dB
Return Loss — Input/Output	IRL/ORL				dB
		20	—	—	
		18	—	—	
Composite Second Order ($V_{out} = +50$ dBmV per Ch., Worst Case) 4-Channel FLAT	CSO_4	—	- 73	- 68	dBc

Table 2. Electrical Characteristics ($V_{CC} = 24 \text{ Vdc}$, $T_C = 30^\circ\text{C}$, 75Ω system, unless otherwise noted) **(continued)**

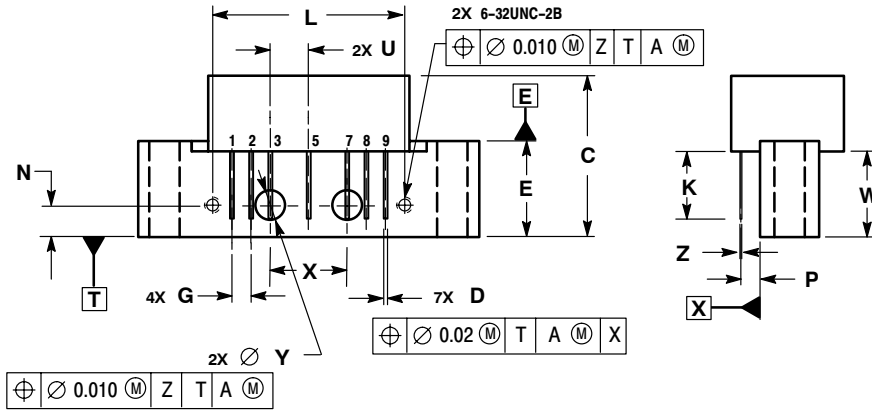
Characteristic	Symbol	Min	Typ	Max	Unit
Cross Modulation Distortion ($V_{out} = +50 \text{ dBmV}$ per Ch., Worst Case) 4-Channel FLAT	XMD_4	—	- 67	- 64	dBc
Composite Triple Beat ($V_{out} = +50 \text{ dBmV}$ per Ch., Worst Case) 4-Channel FLAT	CTB_4	—	- 76	- 74	dBc
Noise Figure ($f = 5\text{-}75 \text{ MHz}$)	NF	—	5	5.7	dB
DC Current	I_{DC}	85	95	110	mA

PACKAGE DIMENSIONS



- NOTES:
 1. CONTROLLING DIMENSION: INCH.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	----	1.775	----	45.085
B	----	1.085	----	27.559
C	----	0.840	----	21.336
D	0.015	0.021	0.381	0.533
E	0.465	0.510	11.811	12.954
F	0.300	0.325	7.620	8.255
G	0.100 BSC		2.540 BSC	
J	0.156 BSC		3.962 BSC	
K	0.315	0.355	8.001	9.017
L	1.000 BSC		25.400 BSC	
N	0.165 BSC		4.191 BSC	
P	0.100 BSC		2.540 BSC	
Q	0.148	0.168	3.759	4.267
R	----	0.600	----	15.240
S	1.500 BSC		38.100 BSC	
U	0.200 BSC		5.080 BSC	
V	----	0.250	----	6.350
W	0.435	----	11.049	----
X	0.400 BSC		10.160 BSC	
Y	0.152	0.163	3.861	4.140
Z	0.009	0.011	0.229	0.279



- STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT

CASE 1302-01
 ISSUE C

How to Reach Us:

Home Page:
www.freescale.com

E-mail:
support@freescale.com

USA/Europe or Locations Not Listed:
Freescale Semiconductor
Technical Information Center, CH370
1300 N. Alma School Road
Chandler, Arizona 85224
+1-800-521-6274 or +1-480-768-2130
support@freescale.com

Europe, Middle East, and Africa:
Freescale Halbleiter Deutschland GmbH
Technical Information Center
Schatzbogen 7
81829 Muenchen, Germany
+44 1296 380 456 (English)
+46 8 52200080 (English)
+49 89 92103 559 (German)
+33 1 69 35 48 48 (French)
support@freescale.com

Japan:
Freescale Semiconductor Japan Ltd.
Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku,
Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:
Freescale Semiconductor Hong Kong Ltd.
Technical Information Center
2 Dai King Street
Tai Po Industrial Estate
Tai Po, N.T., Hong Kong
+800 2666 8080
support.asia@freescale.com

For Literature Requests Only:
Freescale Semiconductor Literature Distribution Center
P.O. Box 5405
Denver, Colorado 80217
1-800-441-2447 or 303-675-2140
Fax: 303-675-2150
LDCForFreescaleSemiconductor@hibbertgroup.com

Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals", must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale™ and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners.
© Freescale Semiconductor, Inc. 2004, 2006. All rights reserved.